

Triak BT131-600;NXP;1A;600V;3mA; TO92;przewlekany THT;RoHS



Dane techniczne:

Nazwa: BT131-600 Typ: Triak Prąd przewodzenia: 1A Napięcie wsteczne: 600V Prąd bramki: 3mA Obudowa: TO92 Montaż: THT Producent: NXP

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1. General description

Planar passivated very sensitive gate four quadrant triac in a SOT54 plastic package intended for interfacing with low power drivers including microcontrollers.

2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing to low power gate drive circuits and microcontrollers
- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants
- Very sensitive gate

3. Applications

- Air conditioner indoor fan control
- General purpose motor control
- General purpose switching

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5	-	-	12.5	A
Tj	junction temperature		-	-	125	°C
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{lead} \le 51.2 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	1	A
Static chara	cteristics	· · · · · · · · · · · · · · · · · · ·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	0.4	3	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	1.3	3	mA





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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	1.4	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	-	3.8	7	mA
Dynamic chara	acteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; R _{GT1} = 1 kΩ; (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	10	20	-	V/µs

5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2		T2T1
2	G	gate		sym051
3	T1	main terminal 1		
			TO-92 (SOT54)	

6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
BT131-600	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54
BT131-600/DG	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54

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7. Limiting values

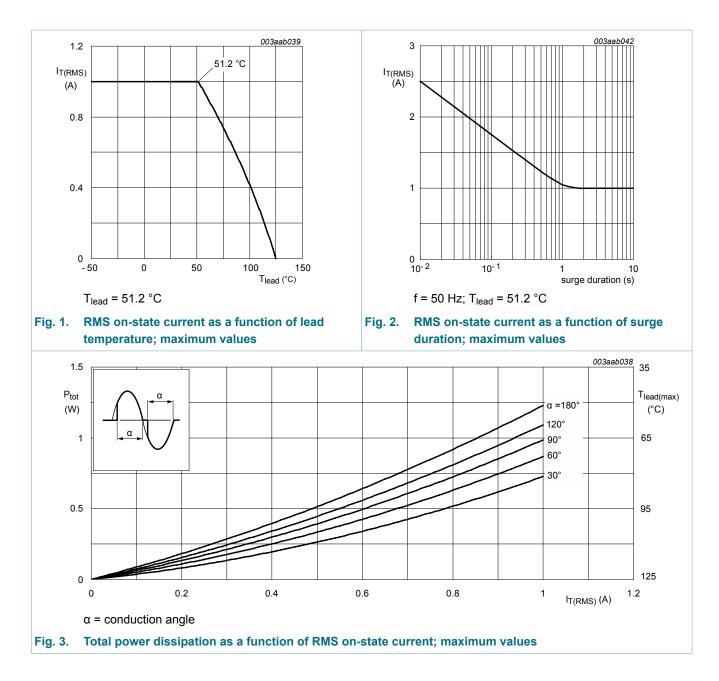
Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{lead} \le 51.2$ °C; Fig. 1; Fig. 2; Fig. 3	-	1	A
I _{TSM}	non-repetitive peak on-state current	full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 20 \text{ ms}; \text{Fig. 4}; \text{Fig. 5}$	-	12.5	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ $t_p = 16.7 \text{ ms}$	-	13.7	A
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	0.78	A ² s
dl _T /dt	rate of rise of on-state current	I_T = 1.5 A; I_G = 20 mA; dI_G/dt = 0.2 A/ µs; T2+ G+	-	50	A/µs
		I_T = 1.5 A; I_G = 20 mA; dI_G/dt = 0.2 A/ µs; T2+ G-	-	50	A/µs
		I_T = 1.5 A; I_G = 20 mA; dI_G/dt = 0.2 A/ µs; T2- G-	-	50	A/µs
		I_T = 1.5 A; I_G = 20 mA; dI_G/dt = 0.2 A/ µs; T2- G+	-	10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C

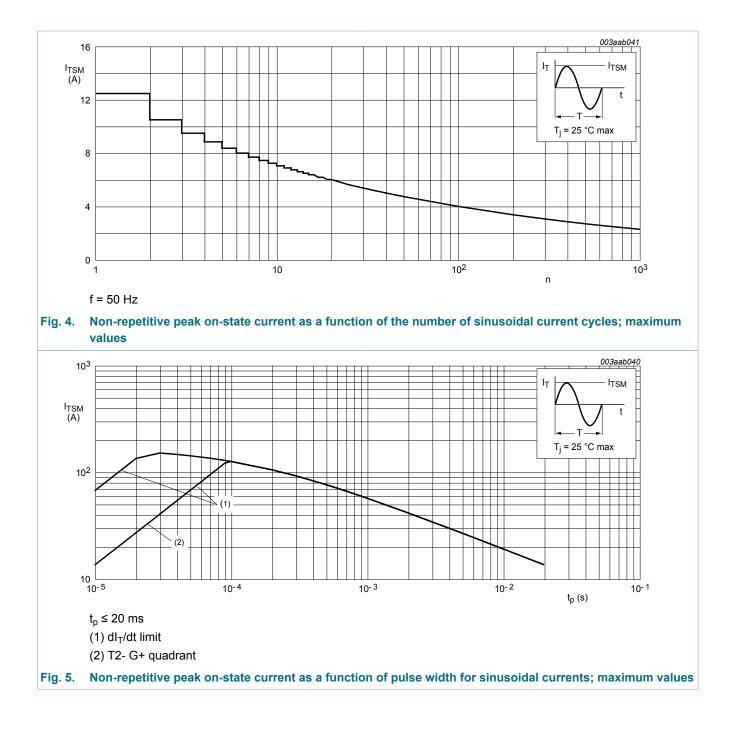
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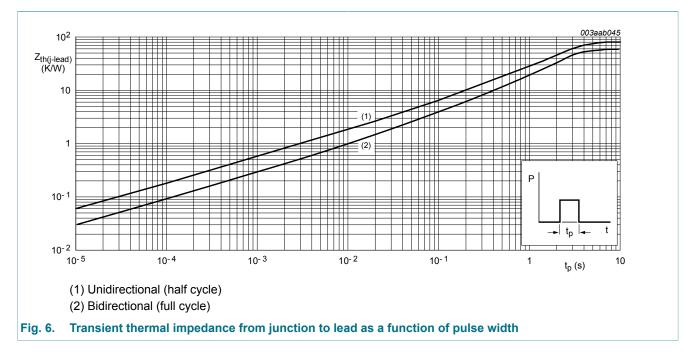
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8. Thermal characteristics

Table 5. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance	full cycle; <u>Fig. 6</u>	-	-	60	K/W
	from junction to lead	half cycle; <u>Fig. 6</u>	-	-	80	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



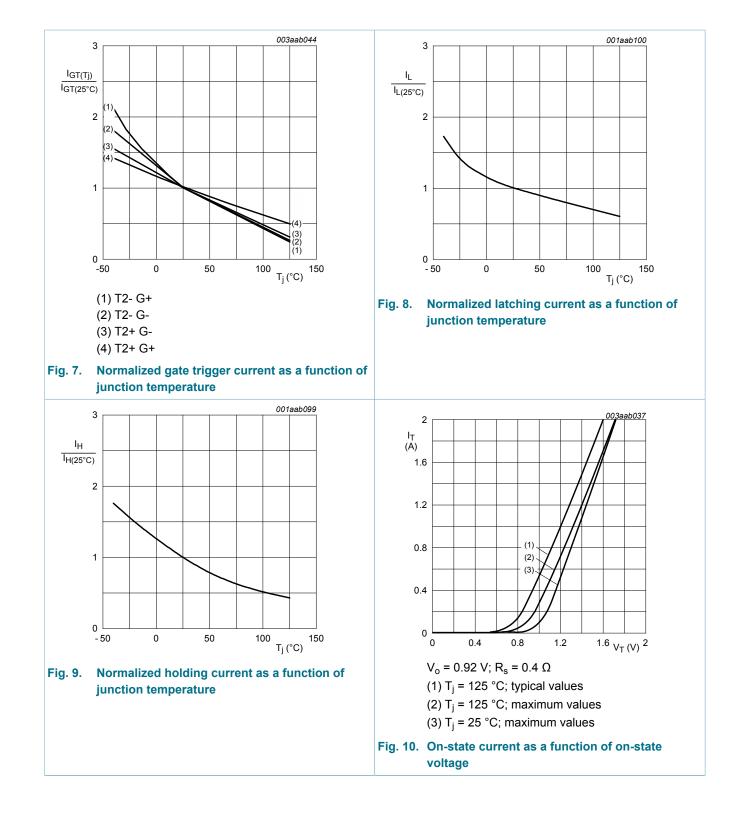
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9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	octeristics		I			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	0.4	3	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	1.3	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	1.4	3	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	-	3.8	7	mA
IL	latching current	V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	1.2	5	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	4	8	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	1	5	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 8</u>	-	2.5	8	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.3	5	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11	0.2	0.3	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic ch	aracteristics	· · · · · · · · · · · · · · · · · · ·				
dV _D /dt	rate of rise of off-state voltage	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ R}_{GT1} = 1 \text{ k}\Omega;$ (V _{DM} = 67% of V _{DRM}); exponential waveform; Fig. 12	10	20	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	V_D = 400 V; T_j = 125 °C; dI_{com} / dt = 0.5 A/ms; I_T = 1 A; gate open circuit	2	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I _{TM} = 1.5 A; V _D = 600 V; I _G = 0.1 A; dI _G / dt = 5 A/μs	-	2	-	μs

BT131-600

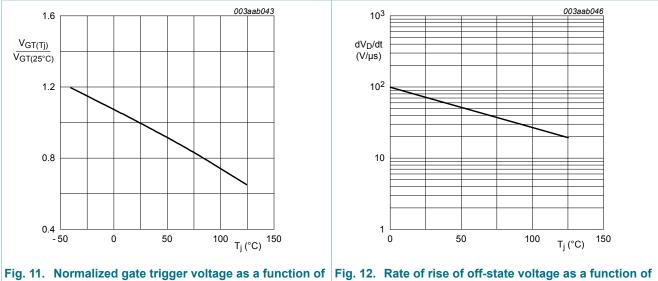
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junction temperature

 Rate of rise of off-state voltage as a function of junction temperature; minimum values

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10. Package outline

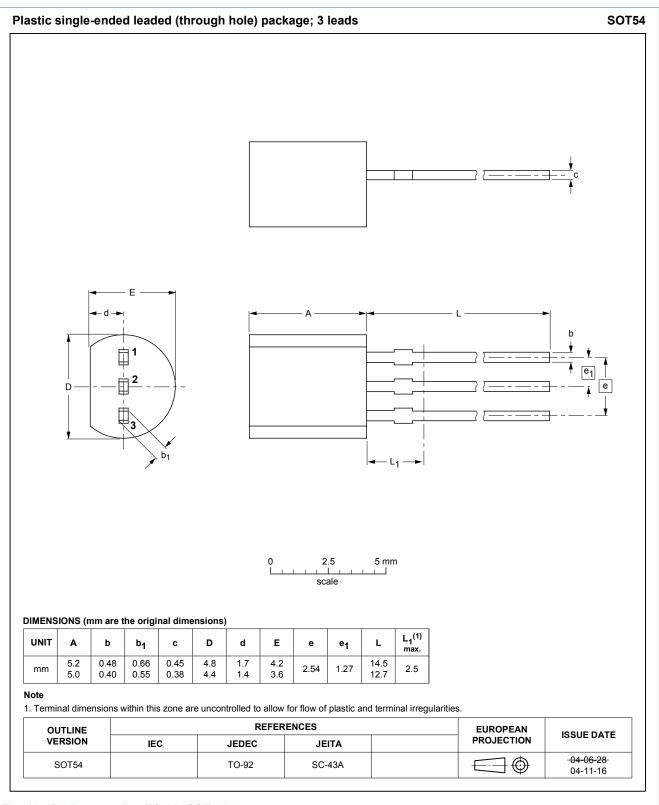


Fig. 13. Package outline TO-92 (SOT54) BT131-600 All information provided in this document is subject to legal disclaimers.

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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[2] The term 'short data sheet' is explained in section "Definitions".

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12. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Limiting values	3
8	Thermal characteristics	6
9	Characteristics	7
-	Characteristics	
10	Package outline	
10 11		10
	Package outline	10 11
11	Package outline Legal information	10 11
11 11.1	Package outline Legal information Data sheet status	10 11 11 11

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